

isc Silicon PNP Power Transistor

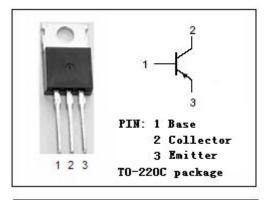
2SB1190

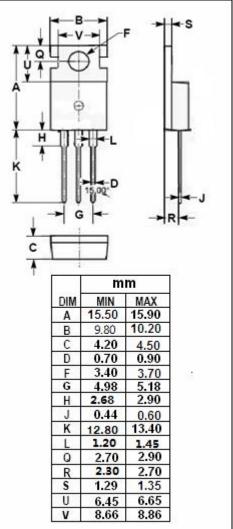
DESCRIPTION

- High Power Dissipation
- High Collector-Emitter Breakdown Voltage-: V_{(BR)CEO}= -150V(Min.)
- Complement to Type 2SD1770
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Power amplifier applications.
- TV vertical deflection output applications.





ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-200	V	
V _{CEO}	Collector-Emitter Voltage	-150	V	
V _{EBO}	Emitter-Base Voltage	-6	V	
lc	Collector Current-Continuous	-1	А	
I _{CM}	Collector Current-Peak	-2	A	
Pc	Total Power Dissipation @ T _c =25℃	25	W	
	Total Power Dissipation @ T _a =25℃	1.4	vv	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -5mA; I _B = 0	-150			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -0.5mA; I _C = 0	-6			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -0.5A; I _B = -50mA			-1.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -0.3A; V _{CE} = -10V			-1.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -200V; I _E = 0			-50	μA
Іево	Emitter Cutoff Current	V _{EB} = -4V; I _C = 0			-50	μA
h _{FE-1}	DC Current Gain	I _C = -0.1A; V _{CE} = -10V	60		240	
h _{FE-2}	DC Current Gain	I _C = -0.3A; V _{CE} = -10V	50			

h_{FE-1} Classifications

Q	Р		
60-140	100-240		

NOTICE:

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